



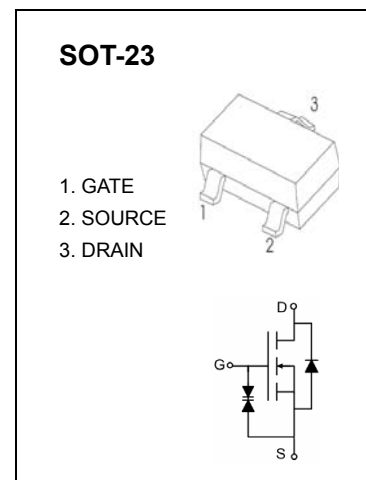
ShenzhenTaimaoTechnology Co.,Ltd.
SOT-23 Plastic-Encapsulate MOSFETS

BSS138K N-Channel 50-V(D-S) MOSFET

FEATURE

- Low On-Resistance
- Low Gate Threshold Voltage
- Fast Switching Speed
- Low Input / Output Leakage

MARKING: SK



Maximum ratings ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	50	V
Continuous Gate-Source Voltage	V_{GSS}	± 12	
Continuous Drain Current	I_D	0.22	A
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	$^{\circ}\text{C}/\text{W}$
Operating Temperature	T_j	150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-55 ~ +150	

Electrical characteristics (T_a=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D =250μA	50			V
Gate-body leakage	I _{GSS}	V _{DS} =0V, V _{GS} =±12V			±1	μA
		V _{DS} =0V, V _{GS} =±10V			±0.5	μA
		V _{DS} =0V, V _{GS} =±5V			±0.05	μA
Zero gate voltage drain current	I _{DSS}	V _{DS} =50V, V _{GS} =0V			0.1	μA
On characteristics						
Gate-threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =0.25mA	0.60		1.20	V
Static drain-source on-resistance	R _{DS(on)}	V _{GS} =1.8V, I _D =0.05A			2.50	Ω
		V _{GS} =2.5V, I _D =0.05A			2.0	
		V _{GS} =5V, I _D =0.05A			1.6	
Forward transconductance	g _{FS}	V _{DS} =10V, I _D =0.2A	0.20			S
Dynamic characteristics*						
Input capacitance	C _{iss}	V _{DS} =25V,V _{GS} =0V, f=1MHz		58		pF
Output capacitance	C _{oss}			9.75		
Reverse transfer capacitance	C _{rss}			5.2		
Gate resistance	R _G	V _{DS} =5V,V _{GS} =10mV, f=1MHz		281		Ω
Switching characteristics*						
Turn-on delay time	t _{d(on)}	V _{DD} =30V, V _{DS} =10V, I _D =0.29A,R _{GEN} =6Ω			5	ns
Rise time	t _r				5	
Turn-off delay time	t _{d(off)}				60	
Fall time	t _f				35	
Drain-source body diode characteristics						
Body diode forward voltage*	V _{SD}	I _S =0.115A, V _{GS} = 0V			1.2	V

* These parameters have no way to verify.